NSN 5962-00-521-2451

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View Online at https://aerobasegroup.com/nsn/5962-00-521-2451

Body Length:

Between 1.200 inches and 1.290 inches

Body Width:

Between 0.515 inches and 0.580 inches

Body Height:

Between 0.120 inches and 0.250 inches

Maximum Power Dissipation Rating:

1.0 watts

Operating Tempurature Range:

-55.0/+85.0 degrees celsius

Storage Tempurature Range:

-65.0/+125.0 degrees celsius

Features Provided:

Monolithic and hermetically sealed and negative outputs and programmable and bipolar and w/storage and w/buffered output and w/decoded

output and high speed

Inclosure Material:

Glass and metal

Inclosure Configuration:

Dual-in-line

Output Logic Form:

P-type metal oxide-semiconductor logic

Input Circuit Pattern:

12 input

Case Outline Source And Designator:

-0-015-aa joint electron device engineering council

Terminal Surface Treatment:

Solder

Voltage Rating And Type Per Characteristic:

-20.0 volts power source and 0.3 volts power source

Time Rating Per Chacteristic:

500.00 nanoseconds propagation delay time, low to high level output and 500.00 nanoseconds propagation delay time, high to low level output

Memory Device Type:

Rom

Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

Terminal Type And Quantity:

24 printed circuit

Shelf Life:

N/a

Unit Of Measure:

Yes - demil/mli

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